NSN 5961-01-349-9021

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-349-9021 **Inclosure Material:** Metal **Overall Length:** Between 0.026 inches and 0.028 inches **Function For Which Designed:** Microwave **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 0.4 forward voltage, dc all semiconductor device diode **Power Rating Per Characteristic:** 75.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Capacitance Rating In Picofarads:** 0.1 all semiconductor device diode and 0.3 all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 beam lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0